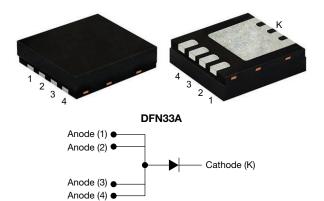


Vishay General Semiconductor

# Surface-Mount TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier



## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub> 9 A								
V <sub>RRM</sub>	200 V							
I <sub>FSM</sub>	150 A							
$V_F$ at $I_F$ = 4.5 A ( $T_J$ = 125 °C)	0.60 V							
T <sub>J</sub> max.	175 °C							
Package	DFN33A							
Circuit configuration	Single							

## FEATURES

- Low profile package typical height of 0.88 mm
- Leadless DFN package with side-wettable flanks suitable for customer AOI (Automatic Optical Inspection)
- Low power losses, high efficiency
- Low forward voltage drop
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **TYPICAL APPLICATIONS**

For use in low voltage, high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

## MECHANICAL DATA

#### Case: DFN33A

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	V9N3202	UNIT				
Device marking code		V922					
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	200	V				
Maximum average forward reptified autrent (fig. 1)	I <sub>F(AV)</sub> <sup>(1)</sup>	9	A				
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub> <sup>(2)</sup>	2.2	A				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	IFSM	150	A				
Operating junction temperature range	T <sub>J</sub> <sup>(3)</sup>	-40 to +175	°C				
Storage temperature range	T <sub>STG</sub>	-55 to +175	°C				

Notes

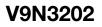
<sup>(1)</sup> With infinite heatsink

<sup>(2)</sup> Free air, mounted on FR4 PCB, 2 oz., standard footprint

 $^{(3)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient: dP<sub>D</sub>/dT<sub>J</sub> < 1/R<sub>0JA</sub>









www.vishay.com

## Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CO	ONDITIONS	SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage	I <sub>F</sub> = 4.5 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.74	-	V		
	I <sub>F</sub> = 9 A	1j=25 C		0.80	0.84			
	I <sub>F</sub> = 4.5 A	T <sub>J</sub> = 125 °C		0.60	-			
	I <sub>F</sub> = 9 A	1j=125 C		0.67	0.71			
Reverse current	V <sub>R</sub> = 160 V	T <sub>J</sub> = 25 °C	I <sub>R</sub> (2)	0.0008	-	mA		
		T <sub>J</sub> = 125 °C		0.7	-			
	V <sub>R</sub> = 200 V	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C		-	0.1			
		T <sub>J</sub> = 125 °C		1.5	7			
Typical junction capacitance	4.0 V, 1 M⊦	lz	CJ	500	-	pF		

Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TYP.	MAX.	UNIT			
	R <sub>0JA</sub> (1)(2)	118	148				
Thermal resistance	R <sub>0JA</sub> <sup>(3)</sup>	-	65	°C/W			
	R <sub>0JM</sub> <sup>(4)</sup>	2.9	3.63				

#### Notes

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

(2) Thermal resistance junction-to-ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint

<sup>(3)</sup> Thermal resistance junction-to-ambient, free air with device mounted on FR4 PCB, 2 oz., 20 mm x 20 mm pad area

<sup>(4)</sup> Thermal resistance junction-to-mount to follow JEDEC 51-14 transient dual interface test method (TDIM)

### **ORDERING INFORMATION TABLE**

		r						
Device code	v	9	N3	20	2	н	М3	
	1	2	3	4	5	6	7	
	1	- Vis	hay TME	3S prod	uct			
	2	- Cur	Current rating (9 = 9 A)					
	3	- Pac	kage ty	pe (N3 =	= DFN33	3A)		
	4	- Vol	tage rati	ng (20 =	= 200 V)			
	5	- TM	BS gene	eration c	ption (2	= Gen2	2)	
	6	- Qua	ality grad	de (H =	AEC-Q1	01 qual	ified, ot	
	7				ental ca nd termi	0,0		

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
V9N3202-M3/I	0.031	I	6000	13" diameter plastic tape and reel				
V9N3202HM3/I <sup>(1)</sup>	0.031	l	6000	13" diameter plastic tape and reel				

#### Note

(1) AEC-Q101 qualified

Revision: 27-Nov-2023

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



## Vishay General Semiconductor

## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

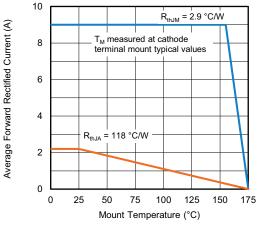
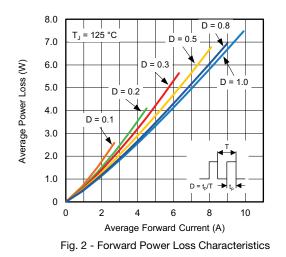


Fig. 1 - Maximum Forward Current Derating Curve



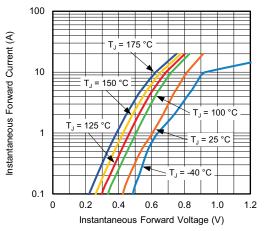
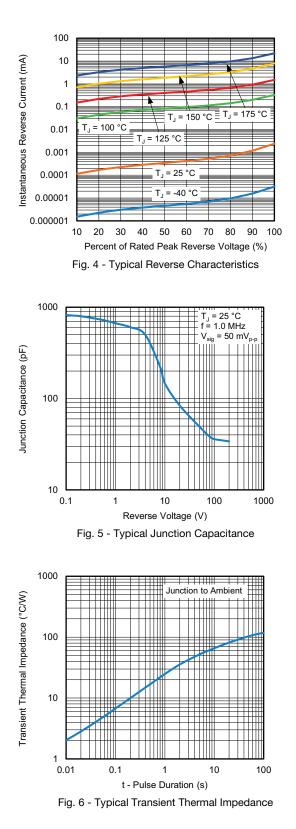


Fig. 3 - Typical Instantaneous Forward Characteristics



Revision: 27-Nov-2023

3

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





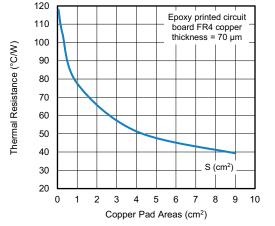


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

Min. 0.005 (0.13) 0.134 (3.40) 0.126 (3.20) 0.039 (0.98) 0.134 (3.40) 0.031 (0.79) 0.126 (3.20) 0.022 (0.55) ref. -Mounting pad layout 0.017 (0.44) 0.011 (0.29) ¥ 0.017 (0.44) 0.094 (2.39) 0.086 (2.19) 0.094 (2.39) 0.030 (0.75) 0.026 (0.65) 0.022 (0.55) ł 0.088 (2.23) - 0.028 (0.70) 0.020 (0.50) 0.028 (0.70) 0.012 (0.30) 0.134 (3.40) 0.088 (2.23) 0.020 (0.50) 0.080 (2.03)

Revision: 27-Nov-2023 Document Number: 98582 4 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

DFN33A



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1